#### SMALL-SIGNAL TRANSISTOR

# 2SA1602

Unit: mm

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE(Super mini type)

2.1

JEITA: SC-70

TERMINAL CONNECTER

: BASE : EMITTER : COLLECTOR

1.25 0.425

OUTLINE DRAWING

2.0

## DESCRIPTION

2SA1602 is a super mini package resin sealed silicon PNP epitaxial transistor,

It is designed for low frequency voltage application.

#### FEATURE

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Small collector to emitter saturation voltage. VCE(sat)=-0.3V max Excellent linearity of DC forward gain.

Super mini package for easy mounting

### APPLICATION

For Hybrid IC,small type machine low frequency voltage Amplify application.

Symbol	Parameter	Ratings	Unit
V <sub>CBO</sub>	Collector to Base voltage	- 50	V
V <sub>CEO</sub>	Collector to Emitter voltage	- 50	V
V <sub>EBO</sub>	Emitter to Base voltage	-6	V
l <sub>o</sub>	Collector current	-200	mA
Pc	Collector dissipation	150	mW
Tj	Junction temperature	unction temperature + 125	
T <sub>stg</sub>	Storage temperature	-55 ~ +125	

## ELECTRICAL CHARACTERISTICS(Ta=25 )

Derometer	Cumbal	bol Test conditions	Limits			11-14
Parameter	Symbol		Min	Тур	Max	Unit
C to E break down voltage	V(BR)CEO	I <sub>c</sub> =-100 μ A ,R <sub>BE</sub> =	-50	-	-	V
Collector cut off current	ICBO	V <sub>CB</sub> =-50V, I <sub>E</sub> =0mA	-	-	-0.1	μA
Emitter cut off current	IEBO	V <sub>EB</sub> =-6V, I <sub>C</sub> =0mA	-	-	-0.1	μA
DC forward current gain	hFE	V <sub>CE</sub> =-6V, I <sub>C</sub> =-1mA	150	-	800	
DC forward current gain	hFE	V <sub>CE</sub> =-6V, I <sub>C</sub> =-0.1mA	90	-	-	
C to E Saturation Vlotage	VCE(sat)	I <sub>c</sub> =-100mA ,I <sub>B</sub> =-10mA	-	-	-0.3	V
Gain bandwidth product	fT	V <sub>CE</sub> =-6V, I <sub>E</sub> =-10mA	-	200	-	MHz
Collector output capacitance	Cob	V <sub>CB</sub> =-6V, I <sub>E</sub> =0,f=1MHz	-	4.0	-	pF

) It shows hFE classification in below table.

ltem	E	F	G
hFE Item	150~300	250~500	400~800

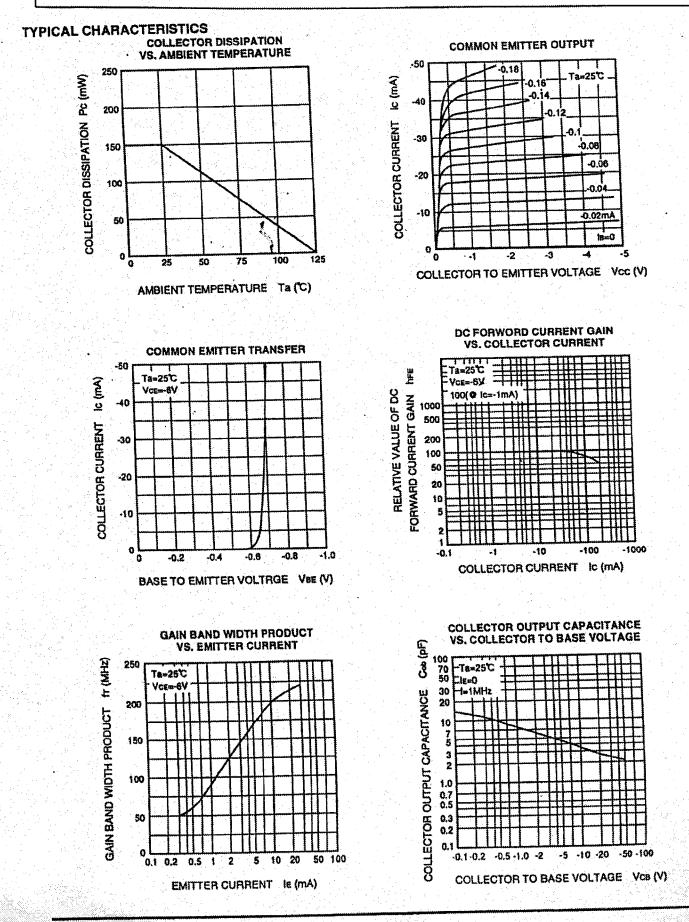
MAXIMUM RATINGS(Ta=25)

ISAHAYA ELECTRONICS CORPORATION

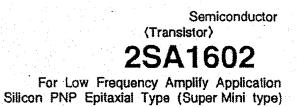
Semiconductor (Transistor)

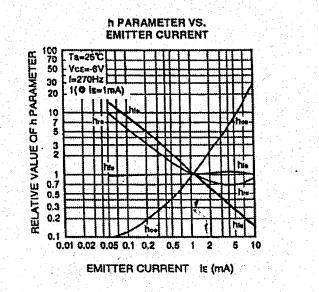
2SA1602

For Low Frequency Amplify Application Silicon PNP Epitaxial Type (Super Mini type)

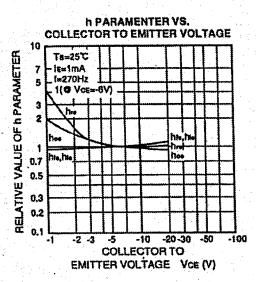


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Free Datasheet http://www//:qff



#### COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	. Umits	Unit
hie	Closed loop small signal input impedance	Ta=25°C	7.0	kΩ
hre	Open loop small signal reverse voltage amplification factor	VCE=-6V	0.1	X10-3
hie	Closed loop small signal forward current amplification factor	le=1mA	250	
 hoe	Open loop small signal output admittance	1=270Hz	18	μS



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#### Keep safety first in your circuit designs!

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